# LMV331 SINGLE, LMV393 DUAL, LMV339 QUAD GENERAL PURPOSE LOW-VOLTAGE COMPARATORS

SLCS136A - AUGUST 1999 - REVISED JANUARY 2000

- 2.7-V and 5-V Performance
- Low Supply Current:

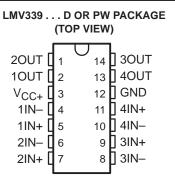
LMV331 . . . 60  $\mu$ A Typ LMV393 . . . 100  $\mu$ A Typ LMV339 . . . 170  $\mu$ A Typ

- Input Common-Mode Voltage Range Includes Ground
- Low Output Saturation Voltage ... 200 mV Typ
- Package Options Include Plastic Small-Outline (D), Small-Outline Transistor (SOT-23 DBV, DCK), and Thin Shrink Small-Outline (PW) Packages

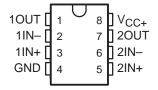
### description

The LMV393 and LMV339 are low-voltage (2.7 V to 5.5 V) versions of the dual and quad comparators, LM393 and LM339, which operate from 5 V to 30 V. The LMV331 is the single-comparator version.

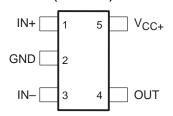
The LMV331, LMV339, and LMV393 are the most cost-effective solutions for applications where low-voltage operation, low power, space saving, and price are the primary specifications in circuit design for portable consumer products. These devices offer specifications that meet or exceed the familiar LM339 and LM393 devices at a fraction of the supply current.







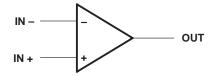
LMV331 ... DBV OR DCK PACKAGE (TOP VIEW)



The LMV331 is available in the ultra-small DCK package, which is approximately half the size of the five-pin SOT-23. The small package saves space on printed circuit boards and enables the design of small portable electronic devices. It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The LMV331, LMV339, and LMV393 devices are characterized for operation from -40°C to 85°C.

### symbol (each comparator)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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#### **AVAILABLE OPTIONS**

т.	PACKAGE	PACKAGED DEVICES			
TA	TYPE	SINGLE	DUAL	QUADRUPLE	
	5-pin DCK 5-pin DBV	LMV331DCKR LMV331DBVR	_ _	_	
−40°C to 85°C	8-pin SOIC 8-pin TSSOP		LMV393D LMV393PWR	_ _	
	14-pin SOIC 14-pin TSSOP	_ _ _	_	LMV339D LMV339PWR	

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LMV393DR). The DCK, DBV, and PW packages are only available left-end taped and reeled.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)	$\dots \dots \pm 5.5 \ V$
Input voltage range, V <sub>I</sub> (either input)	
Package thermal impedance, $\theta_{JA}$ (see Notes 3 and 4): D (8-pin) package	
D (14-pin) package	127°C/W
DBV package	347°C/W
DCK package	389°C/W
PW (8-pin) package	243°C/W
PW (14-pin) package	170°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or PW package	260°C
DBV or DCK package	TBD
Storage temperature range, T <sub>stg</sub>	–65 to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values (except differential voltages and V<sub>CC</sub> specified for the measurement of I<sub>OS</sub>) are with respect to the network GND.
  - 2. Differential voltages are at IN+ with respect to IN-.
  - 3. Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) T<sub>A</sub>)/θ<sub>JA</sub>. Selecting the maximum of 150 °C can impact reliability.
  - 4. The package thermal impedance is calculated in accordance with JESD 51.

## recommended operating conditions

		MIN	MAX	UNIT
VCC	Supply voltage (single-supply operation)	2.7	5.5	V
TA	Operating free-air temperature	-40	85	°C



# PRODUCT PREVIEW

## electrical characteristics at specified free-air temperature, $V_{CC+} = 2.7 \text{ V}$ , GND = 0 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
VIO	Input offset voltage		25°C		1.7	7	mV
$\alpha_{V_{IO}}$	Average temperature coefficient of input offset voltage		-40°C to 85°C		5		μV/°C
	Lament Islam assume at		25°C		10	250	nA
IB	Input bias current		–40°C to 85°C			400	
lia.	land offert summer		25°C		5	50	nA
110	Input offset current		–40°C to 85°C			150	
lo	Output curent	$V_{O} \leq 1.5 V$	25°C	5	23		mA
	Output leakage curent		25°C		0.003		
			–40°C to 85°C			1	μΑ
VICR	Common-mode input voltage range		25°C		-0.1 to 2		V
VSAT	Saturation voltage	$I_O \leq 1 \text{ mA}$	25°C		200		mV
	Supply current	LMV331	25°C		40	100	
Icc		LMV393 (both comparators)	25°C		70	140	μΑ
		LMV339 (all four comparators)	25°C		140	200	

## switching characteristics T<sub>A</sub> = 25°C, V<sub>CC+</sub> = 2.7 V, R<sub>L</sub> = 5.1 k $\Omega$ , GND = 0 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN TYP MAX	UNIT
tPHL	Propagation delay, high- to low-level output switching	Input overdrive = 10 mV	1000	
		Input overdrive = 100 mV	350	ns
t Dranage	Propogation delay low to high level output awitching	Input overdrive = 10 mV	500	ns
tPLH_	Propagation delay, low- to high-level output switching	Input overdrive = 100 mV	400	

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## electrical characteristics at specified free-air temperature, $V_{CC+} = 5 \text{ V}$ , GND = 0 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT
1/10	lanut offeet voltage		25°C		1.7	7	mV
VIO	Input offset voltage		-40°C to 85°C			9	
$\alpha_{V_{10}}$	Average temperature coefficient of input offset voltage		25°C		5		μV/°C
lin.	Land bing summed		25°C		25	250	nA
IB	Input bias current		-40°C to 85°C			400	IIA
lio.	Input offset current		25°C		2	50	nA
110	input onset current		-40°C to 85°C			150	
lo	Output curent	$V_0 \leq 1.5 V$	25°C	10	84		mA
	Output leakage curent		25°C		0.003		μA
			-40°C to 85°C			1	
VICR	Common-mode input voltage range		25°C	-	-0.1 to 4.2		V
AVD	Large-signal differential voltage gain		25°C	20	50		V/mV
\/o	Saturation voltage	$I_{O} \leq 4 \text{ mA}$	25°C		200	400	mV
VSAT			-40°C to 85°C			700	
	Supply current	LMV331	25°C		60	120	
			-40°C to 85°C			150	
		LMV393 (both comparators)	25°C		100	200	μΑ
Icc			-40°C to 85°C			250	
		LMV339 (all four comparators)	25°C		170	300	
			-40°C to 85°C			350	

## switching characteristics at specified free-air temperature , $T_A$ = 25°C, $V_{CC+}$ = 5 V, $R_L$ = 5.1 k $\Omega$ , GND = 0V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN TYP MAX	UNIT
t <sub>PHL</sub> Propaga		Input overdrive = 10 mV	600	ns
	Propagation delay, high- to low-level output switching	Input overdrive = 100 mV	200	
t <sub>PLH</sub> Propagat	Propagation delay low to high level output awitching	Input overdrive = 10 mV	450	ns
	ropagation delay, low- to high-level output switching	Input overdrive = 100 mV	300	



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